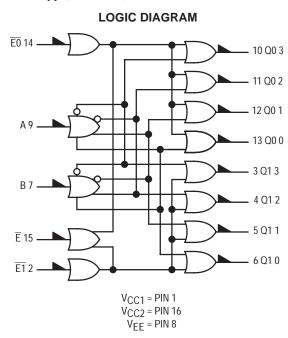
Dual Binary to 1-4 Decoder (Low)

The MC10171 is a binary coded 2 line to dual 4 line decoder with selected outputs low. With either $\overline{E}0$ or $\overline{E}1$ high, the corresponding selected 4 outputs are high. The common enable \overline{E} , when high, forces all outputs high.

- $P_D = 325 \text{ mW typ/pkg (No Load)}$
- $t_{pd} = 4.0 \text{ ns typ}$
- t_r , $t_f = 2.0$ ns typ (20%–80%)



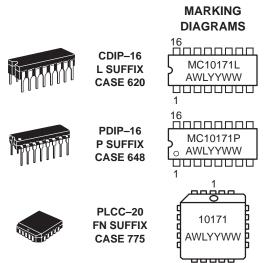
TRUTH TABLE

ENAE	LE INF	PUTS	INP	JTS	OUTPUTS							
Ē	E0	E1	Α	В	Q10	Q11	Q12	Q13	Q00	Q01	Q02	Q03
L	L	L	L	L	L	Н	Н	Н	L	Н	Н	Н
L	L	L	L	Н	Н	L	Н	Н	Н	L	Н	Н
L	L	L	Н	L	Н	Н	L	Н	Н	Н	L	Н
L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	L
L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н
L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
Н	Х	Χ	Χ	Χ	Н	Н	Н	Н	Н	Н	Н	Н



ON Semiconductor

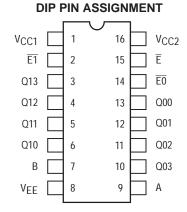
http://onsemi.com



WL = Wafer Lot YY = Year

WW = Work Week

= Assembly Location



Pin assignment is for Dual–in–Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).

ORDERING INFORMATION

Device	Package	Shipping					
MC10171L	CDIP-16	25 Units / Rail					
MC10171P	PDIP-16	25 Units / Rail					
MC10171FN	PLCC-20	46 Units / Rail					

ELECTRICAL CHARACTERISTICS

				Test Limits							
			Pin Under	−30°C		+25°C			+85°C		1
Chara	cteristic	Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	Unit
Power Supply Drain Current		ΙE	8		85		65	77		85	mAdc
Input Current	:	linH	14		350			220		220	μAdc
		l _{inL}	14	0.5		0.5			0.3		μAdc
Output Voltag	ge Logic 1	Voн	6 13	-1.060 -1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	Vdc
Output Voltag	ge Logic 0	VOL	13	-1.890	-1.675	-1.850		-1.650	-1.825	-1.615	Vdc
Threshold Vo	oltage Logic 1	Vона	6 13	-1.080 -1.080		-0.980 -0.980			-0.910 -0.910		Vdc
Threshold Vo	oltage Logic 0	VOLA	6 13		-1.655 -1.655			-1.630 -1.630		-1.595 -1.595	Vdc
Switching Tim	nes (50Ω Load)										ns
Propagation [Delay	t ₇₊₆₊ t ₇₋₆₋ t ₇₊₁₃₊ t ₇₋₁₃₋	6 6 13 13	1.5 1.5 1.5 1.5	6.2 6.2 6.2 6.2	1.5 1.5 1.5 1.5	4.0 4.0 4.0 4.0	6.0 6.0 6.0 6.0	1.5 1.5 1.5 1.5	6.4 6.4 6.4 6.4	
Rise Time	(20 to 80%)	^t 6+ ^t 13+	6 13	1.0 1.0	3.3 3.3	1.1 1.1	2.0 2.0	3.3 3.3	1.1 1.1	3.4 3.4	
Fall Time	(20 to 80%)	t ₆₋ t ₁₃₋	6 13	1.0 1.0	3.3 3.3	1.1 1.1	2.0 2.0	3.3 3.3	1.1 1.1	3.4 3.4	

ELECTRICAL CHARACTERISTICS (continued)

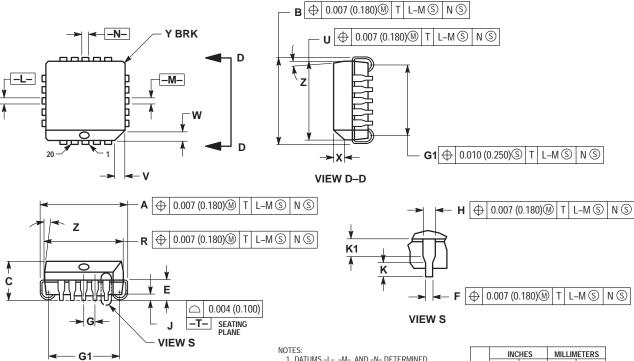
					TEST VOL	TAGE VALU	ES (Volts)		
	V _{IHmax}	V _{ILmin}	VIHAmin	V _{ILAmax}	VEE				
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
			Pin	TEST V	OLTAGE APP	LIED TO PI	NS LISTED B	ELOW	
Characteri	istic	Symbol	Under Test	V _{IHmax}	V _{ILmin}	VIHAmin	V _{ILAmax}	VEE	(VCC)
Power Supply Drain	Current	ΙΕ	8	2,7,9,14,15				8	1, 16
Input Current		linH	14	14				8	1, 16
		l _{inL}	14		14			8	1, 16
Output Voltage	Logic 1	Vон	6 13	15 15				8 8	1, 16 1, 16
Output Voltage	Logic 0	VOL	13		2,7,9,14,15			8	1, 16
Threshold Voltage	Logic 1	Vона	6 13			15 15		8 8	1, 16 1, 16
Threshold Voltage	Logic 0	VOLA	6 13		2,9,14,15 2,7,14,15		7 9	8 8	1, 16 1, 16
Switching Times	(50Ω Load)				+0.31V	Pulse In	Pulse Out	-3.2 V	+2.0 V
Propagation Delay		t ₇₊₆₊ t ₇₋₆₋ t ₇₊₁₃₊ t ₇₋₁₃₋	6 6 13 13		2,9,14,15 2,9,14,15 2,9,14,15 2,9,14,15	7 7 7 7	6 6 13 13	8 8 8	1, 16 1, 16 1, 16 1, 16
Rise Time	(20 to 80%)	^t 6+ t ₁₃₊	6 13			7 7	6 13	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t ₆₋ t ₁₃₋	6 13			7 7	6 13	8 8	1, 16 1, 16

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



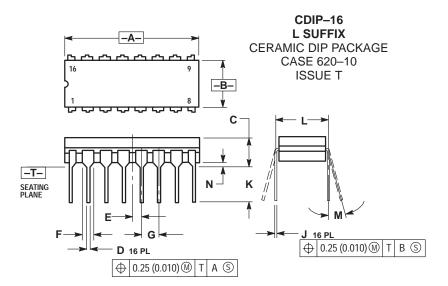
⊕ 0.010 (0.250)⑤ T L-M ⑤ N ⑤

- DATUMS -L-, -M-, AND -N- DETERMINED
 WHERE TOP OF LEAD SHOULDER EXITS PLASTIC WILLY LOVE LEAD STOUDER EXTENSIVE SOLUTION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD
- FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
 4. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH.
- 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

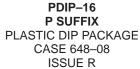
	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.385	0.395	9.78	10.03
В	0.385	0.395	9.78	10.03
С	0.165	0.180	4.20	4.57
Ε	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.350	0.356	8.89	9.04
U	0.350	0.356	8.89	9.04
V	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
Х	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2°	10 °	2 °	10 °
G1	0.310	0.330	7.88	8.38
K1	0.040		1.02	

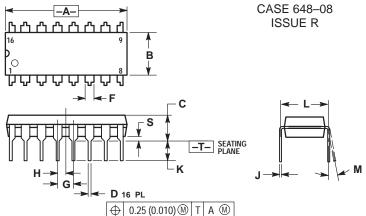
PACKAGE DIMENSIONS



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Ε	0.050	BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300	BSC	7.62 BSC		
M	0°	15°	0°	15°	
N	0.020	0.040	0.51	1.01	





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54 BSC			
Н	0.050	BSC	1.27 BSC			
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
M	0°	10 °	0 °	10 °		
S	0.020	0.040	0.51	1.01		

Notes

Notes

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